



## AO3406

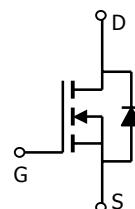
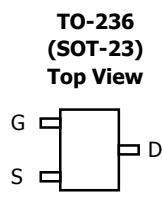
### N-Channel Enhancement Mode Field Effect Transistor

#### General Description

The AO3406 uses advanced trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. This device is suitable for use as a load switch or in PWM applications.

#### Features

$V_{DS}$  (V) = 30V  
 $I_D$  = 3.6 A  
 $R_{DS(ON)} < 65\text{m}\Omega$  ( $V_{GS} = 10\text{V}$ )  
 $R_{DS(ON)} < 105\text{m}\Omega$  ( $V_{GS} = 4.5\text{V}$ )



#### Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>A</sup>	$I_D$	3.6	A
$T_A=70^\circ\text{C}$		2.9	
Pulsed Drain Current <sup>B</sup>	$I_{DM}$	15	
Power Dissipation <sup>A</sup>	$P_D$	1.4	W
$T_A=70^\circ\text{C}$		0.9	
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	°C

#### Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient <sup>A</sup>	$R_{\theta JA}$	70	90	°C/W
Steady-State		100	125	°C/W
Maximum Junction-to-Lead <sup>C</sup>	$R_{\theta JL}$	63	80	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>STATIC PARAMETERS</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$I_D=250\mu\text{A}, V_{\text{GS}}=0\text{V}$	30			V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}}=24\text{V}, V_{\text{GS}}=0\text{V}$ $T_J=55^\circ\text{C}$			1	$\mu\text{A}$
$I_{\text{GSS}}$	Gate-Body leakage current	$V_{\text{DS}}=0\text{V}, V_{\text{GS}}=\pm20\text{V}$			5	$\text{nA}$
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}, I_D=250\mu\text{A}$	1	1.9	3	V
$I_{\text{D(ON)}}$	On state drain current	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=5\text{V}$	15			A
$R_{\text{DS(ON)}}$	Static Drain-Source On-Resistance	$V_{\text{GS}}=10\text{V}, I_D=3.6\text{A}$ $T_J=125^\circ\text{C}$		50	65	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_D=2.8\text{A}$		74	100	$\text{m}\Omega$
$g_{\text{FS}}$	Forward Transconductance	$V_{\text{DS}}=5\text{V}, I_D=3.6\text{A}$		75	105	$\text{m}\Omega$
$V_{\text{SD}}$	Diode Forward Voltage	$I_S=1\text{A}$		0.79	1	V
$I_S$	Maximum Body-Diode Continuous Current				2.5	A
<b>DYNAMIC PARAMETERS</b>						
$C_{\text{iss}}$	Input Capacitance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=15\text{V}, f=1\text{MHz}$		288		$\text{pF}$
$C_{\text{oss}}$	Output Capacitance			57		$\text{pF}$
$C_{\text{rss}}$	Reverse Transfer Capacitance			39		$\text{pF}$
$R_g$	Gate resistance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, f=1\text{MHz}$		3		$\Omega$
<b>SWITCHING PARAMETERS</b>						
$Q_g(10\text{V})$	Total Gate Charge	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, I_D=3.6\text{A}$		6.5		$\text{nC}$
$Q_g(4.5\text{V})$	Total Gate Charge			3.1		$\text{nC}$
$Q_{\text{gs}}$	Gate Source Charge			1.2		$\text{nC}$
$Q_{\text{gd}}$	Gate Drain Charge			1.6		$\text{nC}$
$t_{\text{D(on)}}$	Turn-On DelayTime	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, R_L=2.2\Omega, R_{\text{GEN}}=3\Omega$		4.6		ns
$t_r$	Turn-On Rise Time			1.9		ns
$t_{\text{D(off)}}$	Turn-Off DelayTime			20.1		ns
$t_f$	Turn-Off Fall Time			2.6		ns
$t_{\text{rr}}$	Body Diode Reverse Recovery Time	$I_F=3.6\text{A}, dI/dt=100\text{A}/\mu\text{s}$		10.2		ns
$Q_{\text{rr}}$	Body Diode Reverse Recovery Charge	$I_F=3.6\text{A}, dI/dt=100\text{A}/\mu\text{s}$		3.5		$\text{nC}$

A: The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any given application depends on the user's specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The  $R_{\theta JA}$  is the sum of the thermal impedance from junction to lead  $R_{\theta JL}$  and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80  $\mu\text{s}$  pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The SOA curve provides a single pulse rating.

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

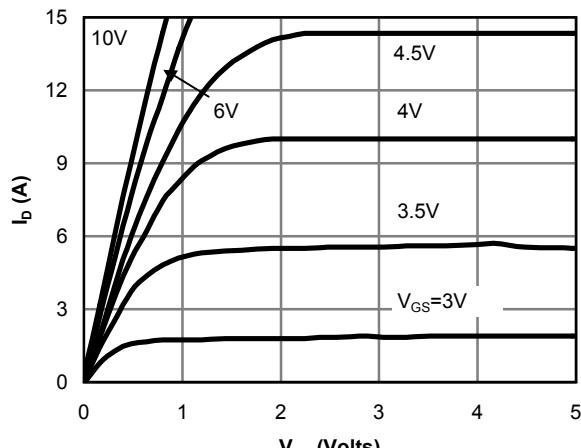


Fig 1: On-Region Characteristics

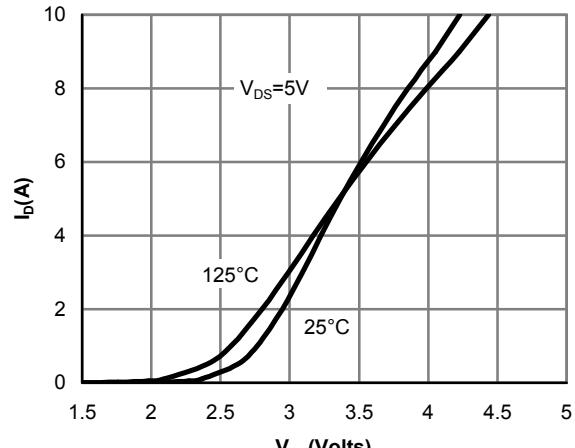


Figure 2: Transfer Characteristics

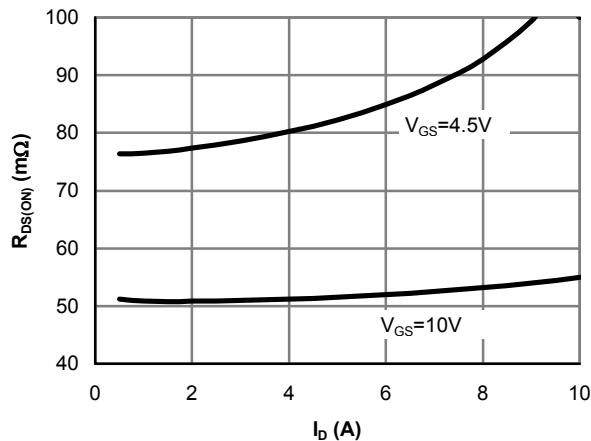


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

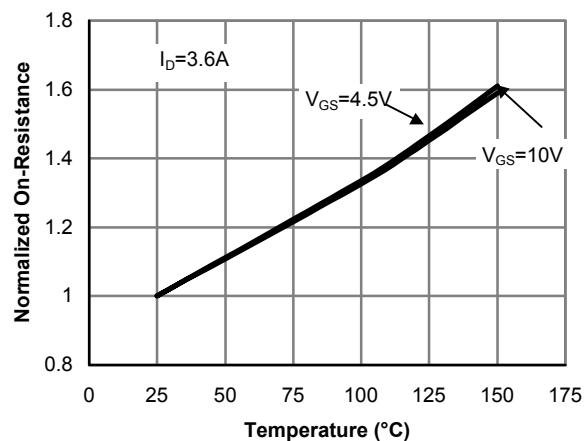


Figure 4: On-Resistance vs. Junction Temperature

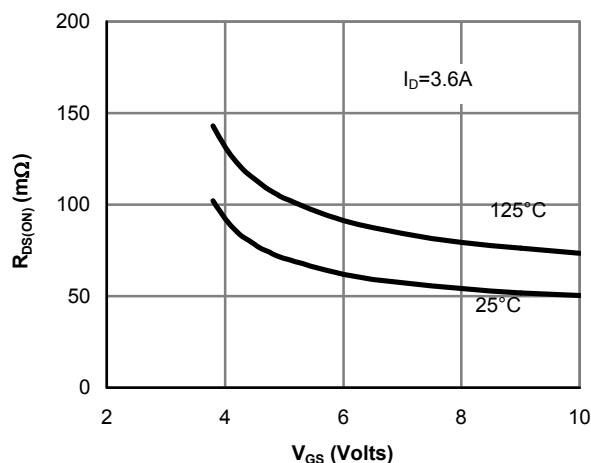


Figure 5: On-Resistance vs. Gate-Source Voltage

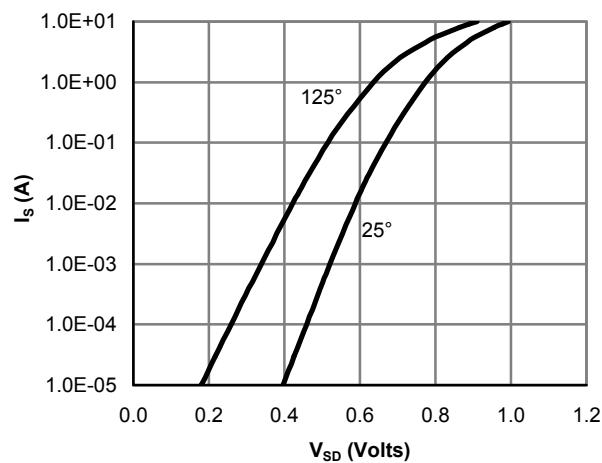
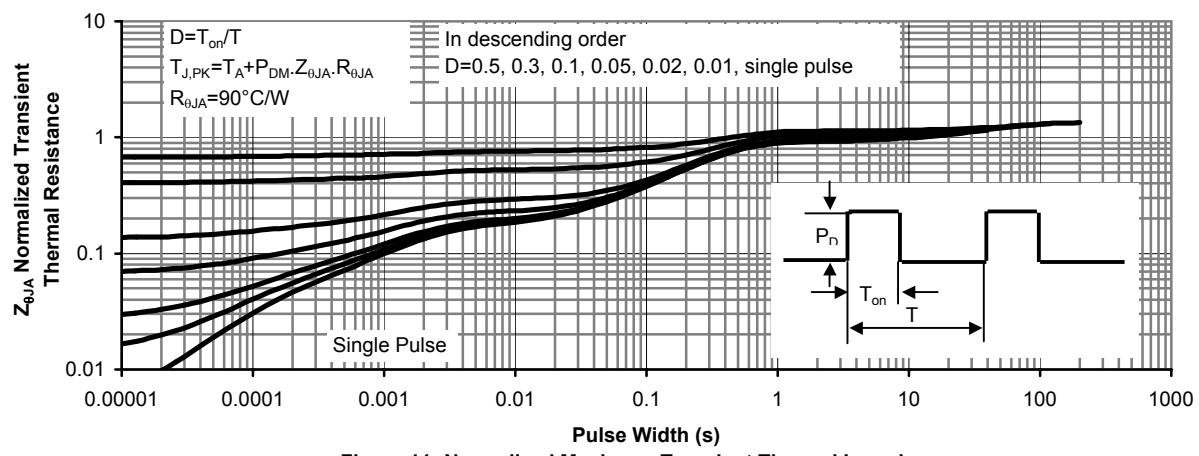
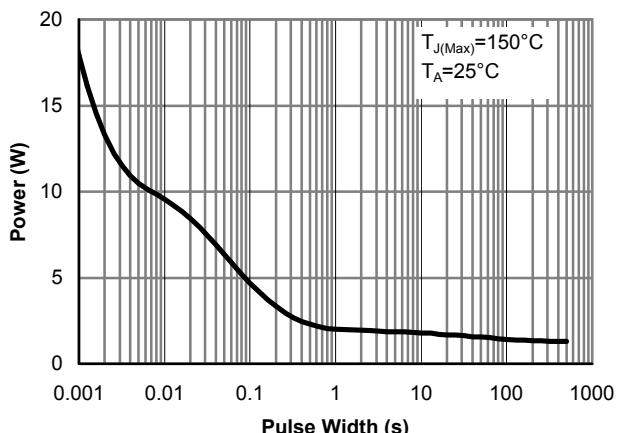
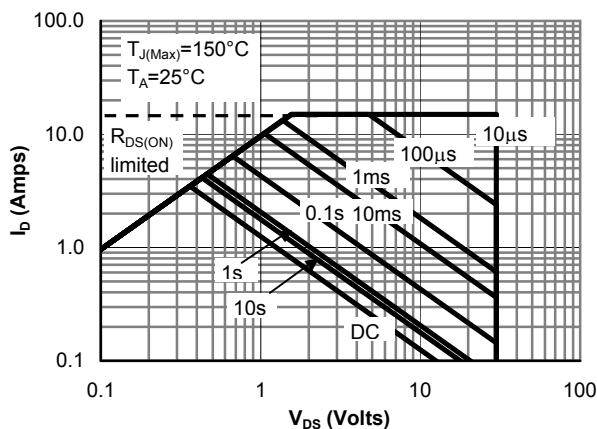
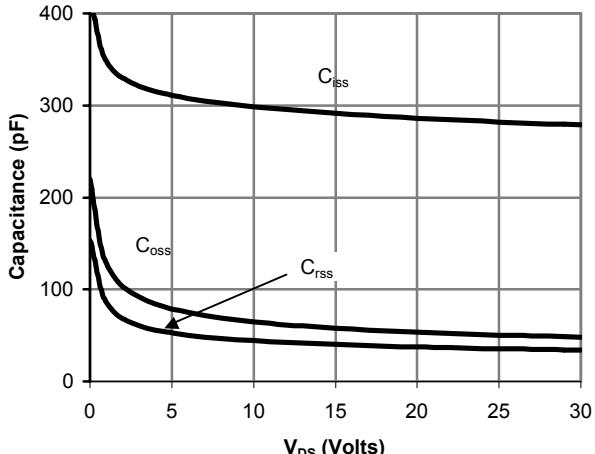
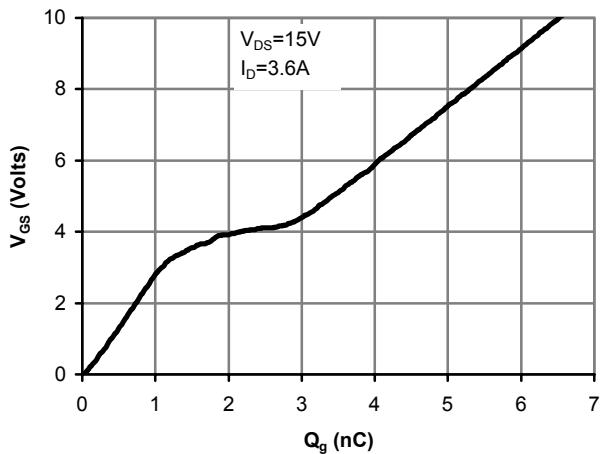


Figure 6: Body-Diode Characteristics

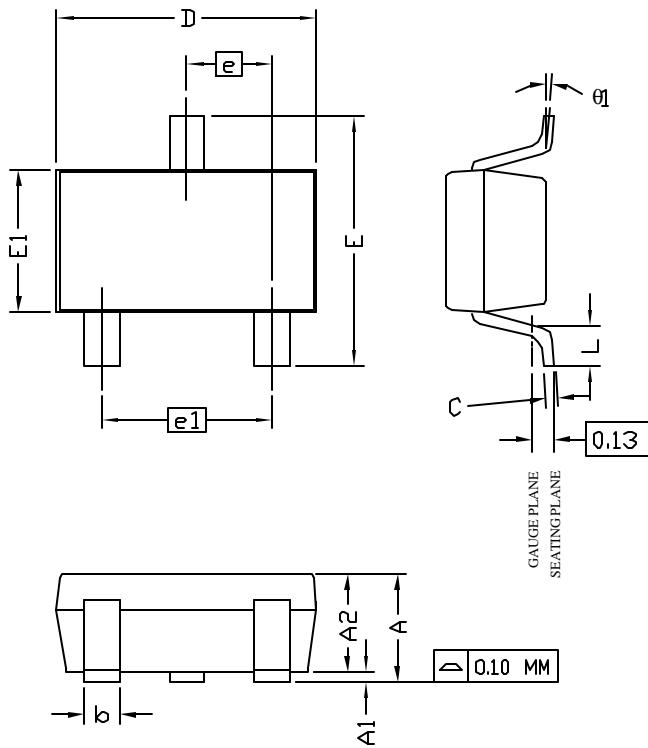
## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS





**ALPHA & OMEGA**  
SEMICONDUCTOR, INC.

## SOT-23 Package Data

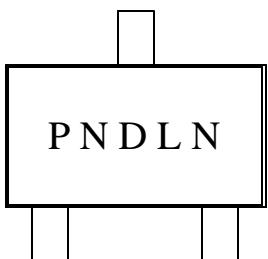


SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	1.00	—	1.25
A1	0.00	—	0.10
A2	1.00	1.10	1.15
b	0.35	0.40	0.50
C	0.10	0.15	0.25
D	2.80	2.90	3.04
E	2.60	2.80	2.95
E1	1.40	1.60	1.80
e	—	0.95 BSC	—
el	—	1.90 BSC	—
L	0.40	—	0.60
θ1	1°	5°	8°

NOTE:

1. LEAD FINISH: 150 MICROINCHES ( 3.8  $\mu$ m) MIN.  
THICKNESS OF Tin/Lead (SOLDER) PLATED ON LEAD
2. TOLERANCE  $\pm 0.10$  mm (4 mil) UNLESS OTHERWISE  
SPECIFIED
3. COPLANARITY : 0.10 mm
4. DIMENSION L IS MEASURED IN GAGE PLANE

### PACKAGE MARKING DESCRIPTION

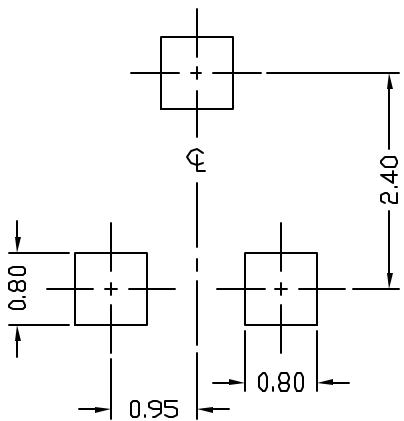


#### SOT-23 PART NO. CODE

PART NO.	CODE
AO3406	A6

NOTE:  
P N - PART NUMBER CODE.  
D - YEAR AND WEEK CODE.  
L N - ASSEMBLY LOT CODE, FAB AND  
ASSEMBLY LOCATION CODE.

### RECOMMENDATION OF LAND PATTERN

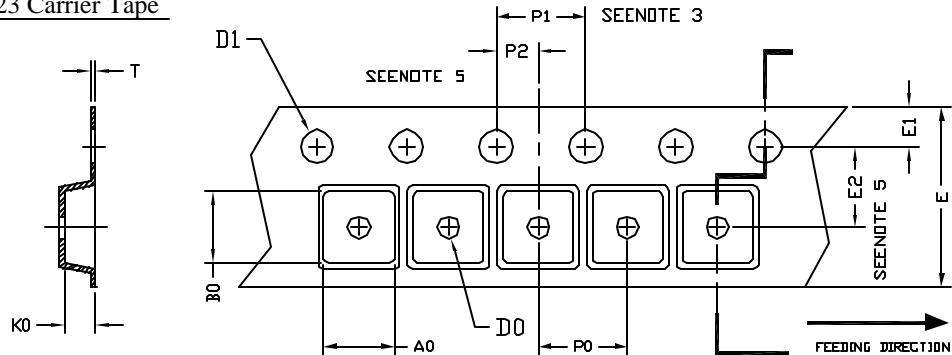




**ALPHA & OMEGA**  
SEMICONDUCTOR, INC.

## SOT-23 Tape and Reel Data

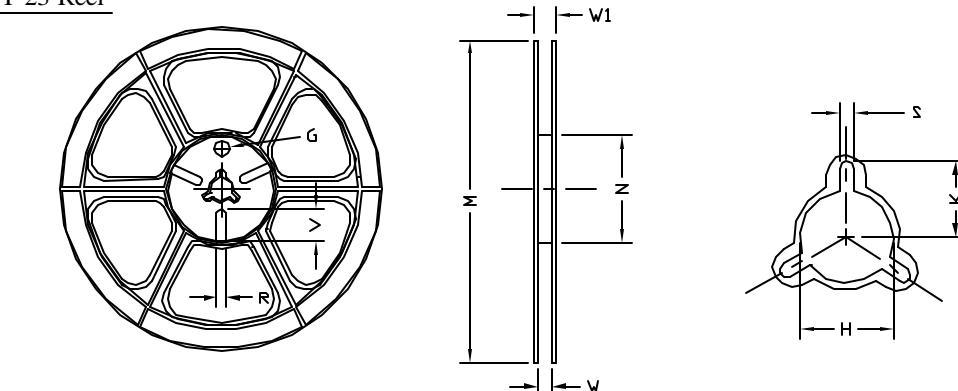
### SOT-23 Carrier Tape



UNIT: MM

PACKAGE	$A_0$	$B_0$	$K_0$	$D_0$	$D_1$	$E$	$E_1$	$E_2$	$P_0$	$P_1$	$P_2$	$T$
SOT-23 (8 mm)	3.15 $\pm 0.10$	3.20 $\pm 0.10$	1.40 $\pm 0.10$	1.00 MIN	1.50 $+0.10$	8.00 $\pm 0.30$	1.75 $\pm 0.10$	3.50 $\pm 0.05$	4.00 $\pm 0.10$	4.00 $\pm 0.10$	2.00 $\pm 0.05$	0.25 $\pm 0.05$

### SOT-23 Reel



UNIT: MM

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8 mm	$\phi 180$	$\phi 180.00$ $\pm 0.50$	$\phi 60.50$	9.00 $\pm 0.30$	11.40 $\pm 1.00$	$\phi 13.00$ $+0.50$ $-0.20$	10.60	2.00 $\pm 0.50$	$\phi 9.00$	5.00	18.00

### SOT-23 Tape

Leader / Trailer  
& Orientation

